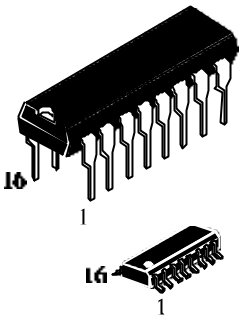
1- of-8 Decoder/Demultiplexer

High-Performance Silicon-Gate CMOS



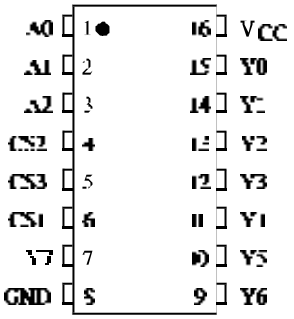
ORDERING INFORMATION
SL74HCT138N Plastic
SL74HCT138D SOIC
T_A = -55° to 125° C for all packages

The SL74HCT138 is identical in pinout to the LS/ALS138. The SL74HCT138 may be used as a level converter for interfacing TTL or NMOS outputs to High Speed CMOS inputs.

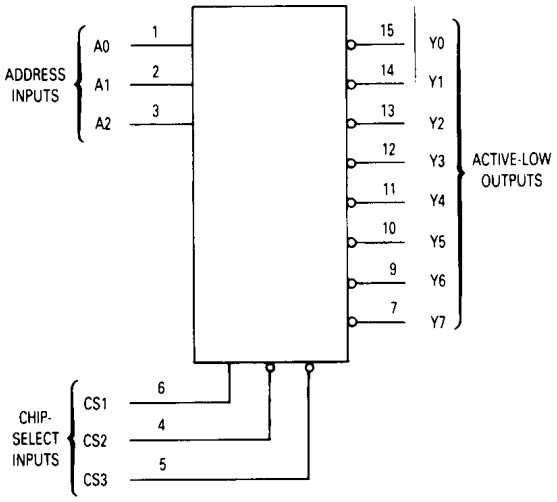
The SL74HCT138 decodes a three-bit Address to one-of-eight active-lot outputs. This device features three Chip Select inputs, two active-low and one active-high to facilitate the demultiplexing, cascading, and chip-selecting functions. The demultiplexing function is accomplished by using the Address inputs to select the desired device output; one of the Chip Selects is used as a data input while the other Chip Selects are held in their active states.

- TTL/NMOS Compatible Input Levels
- Outputs Directly Interface to CMOS, NMOS, and TTL
- Operating Voltage Range: 4.5 to 5.5 V
- Low Input Current: 1.0 μA

PIN ASSIGNMENT



LOGIC DIAGRAM



PIN 16 = V_{CC}
PIN 8 = GND

FUNCTION TABLE

Inputs		Outputs
CS1 CS2 CS3	A2 A1 A0	Y0 Y1 Y2 Y3 Y4 Y5 Y6 Y7
X X H	X X X	H H H H H H H H
X H X	X X X	H H H H H H H H
L X X	X X X	H H H H H H H H
H L L	L L L	L H H H H H H H
H L L	L L H	H L H H H H H H
H L L	L H L	H H L H H H H H
H L L	L H H	H H H L H H H H
H L L	H L L	H H H H L H H H
H L L	H L H	H H H H H L H H
H L L	H H L	H H H H H H L H
H L L	H H H	H H H H H H H L

H = high level (steady state)
L = low level (steady state)
X = don't care

MAXIMUM RATINGS*

Symbol	Parameter	Value	Unit
V_{CC}	DC Supply Voltage (Referenced to GND)	-0.5 to +7.0	V
V_{IN}	DC Input Voltage (Referenced to GND)	-1.5 to V_{CC} +1.5	V
V_{OUT}	DC Output Voltage (Referenced to GND)	-0.5 to V_{CC} +0.5	V
I_{IN}	DC Input Current, per Pin	±20	mA
I_{OUT}	DC Output Current, per Pin	±25	mA
I_{CC}	DC Supply Current, V_{CC} and GND Pins	±50	mA
P_D	Power Dissipation in Still Air, Plastic DIP+ SOIC Package+	750 500	mW
Tstg	Storage Temperature	-65 to +150	°C
T_L	Lead Temperature, 1 mm from Case for 10 Seconds (Plastic DIP or SOIC Package)	260	°C

*Maximum Ratings are those values beyond which damage to the device may occur.
Functional operation should be restricted to the Recommended Operating Conditions.
+Derating - Plastic DIP: - 10 mW/°C from 65° to 125°C
SOIC Package: : - 7 mW/°C from 65° to 125°C

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit
V_{CC}	DC Supply Voltage (Referenced to GND)	4.5	5.5	V
V_{IN}, V_{OUT}	DC Input Voltage, Output Voltage (Referenced to GND)	0	V_{CC}	V
T_A	Operating Temperature, All Package Types	-55	+125	°C
t_r, t_f	Input Rise and Fall Time (Figure 2)	0	500	ns

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation, V_{IN} and V_{OUT} should be constrained to the range GND≤(V_{IN} or V_{OUT})≤V_{CC}.

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V_{CC}). Unused outputs must be left open.

DC ELECTRICAL CHARACTERISTICS(Voltages Referenced to GND)

Symbol	Parameter	Test Conditions	V_{CC} V	Guaranteed Limit			Unit
				25 °C to -55°C	≤85 °C	≤125 °C	
V_{IH}	Minimum High-Level Input Voltage	V_{OUT}=0.1 V or V_{CC}-0.1 V $\|I_{OUT}\| \leq 20\ \mu A$	4.5 5.5	2.0 2.0	2.0 2.0	2.0 2.0	V
V_{IL}	Maximum Low -Level Input Voltage	V_{OUT}=0.1 V or V_{CC}-0.1 V $\|I_{OUT}\| \leq 20\ \mu A$	4.5 5.5	0.8 0.8	0.8 0.8	0.8 0.8	V
V_{OH}	Minimum High-Level Output Voltage	V_{IN}=V_{IH} or V_{IL} $\|I_{OUT}\| \leq 20\ \mu A$	4.5 5.5	4.4 5.4	4.4 5.4	4.4 5.4	V
		V_{IN}=V_{IH} or V_{IL} $\|I_{OUT}\| \leq 4.0$ mA	4.5	3.98	3.84	3.7	
V_{OL}	Maximum Low-Level Output Voltage	V_{IN}=V_{IH} or V_{IL} $\|I_{OUT}\| \leq 20\ \mu A$	4.5 5.5	0.1 0.1	0.1 0.1	0.1 0.1	V
		V_{IN}=V_{IH} or V_{IL} $\|I_{OUT}\| \leq 4.0$ mA	4.5	0.26	0.33	0.4	
I_{IN}	Maximum Input Leakage Current	V_{IN}=V_{CC} or GND	5.5	±0.1	±1.0	±1.0	μA
I_{CC}	Maximum Quiescent Supply Current (per Package)	V_{IN}=V_{CC} or GND I_{OUT}=0μA	5.5	4.0	40	160	μA
ΔI_{CC}	Additional Quiescent Supply Current	V_{IN} = 2.4 V, Any One Input V_{IN}=V_{CC} or GND, Other Inputs		≥-55°C		25°C to 125°C	mA
		I_{OUT}=0μA	5.5	2.9		2.4	

AC ELECTRICAL CHARACTERISTICS (V_{CC} =5.0 V, C_L=50pF,Input t_r=t_f=6.0 ns)

Symbol	Parameter	Guaranteed Limit			Unit
		25 °C to -55°C	≤85°C	≤125°C	
t_{PLH}, t_{PHL}	Maximum Propagation Delay, Input A to Output Y (Figures 1 and 4)	30	38	45	ns
t_{PLH}, t_{PHL}	Maximum Propagation Delay , CS1 to Output Y (Figures 2 and 4)	27	34	41	ns
t_{PLH}, t_{PHL}	Maximum Output Transition Time , CS2 or CS3 to Output Y (Figures 3 and 4)	30	38	45	ns
t_{TLH}, t_{THL}	Maximum Output Transition Time, Any Output (Figures 2 and 4)	15	19	22	ns
C_{IN}	Maximum Input Capacitance	10	10	10	pF

C_{PD}	Power Dissipation Capacitance (Per Enabled Output) Used to determine the no-load dynamic power consumption: $P_D=C_{PD}V_{CC}^2f+I_{CC}V_{CC}$	Typical @25°C,V_{CC}=5.0 V 51	pF

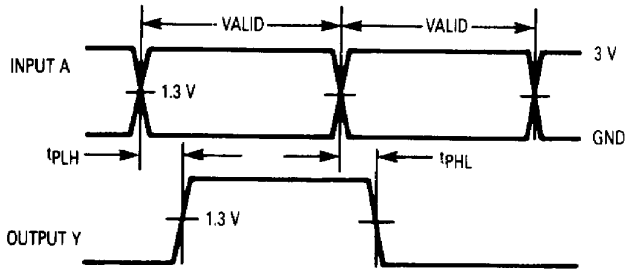


Figure 1. Switching Waveforms

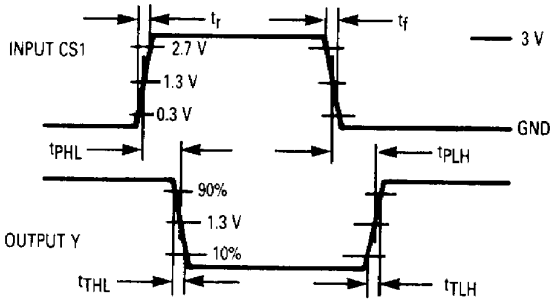


Figure 2. Switching Waveforms

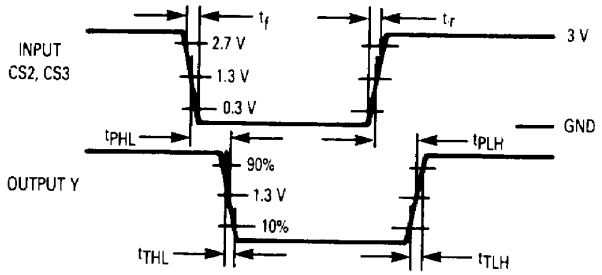


Figure 3. Switching Waveforms

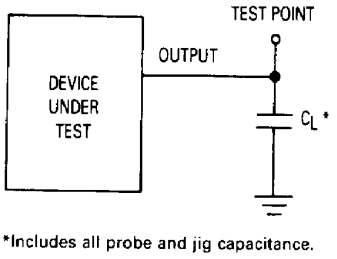
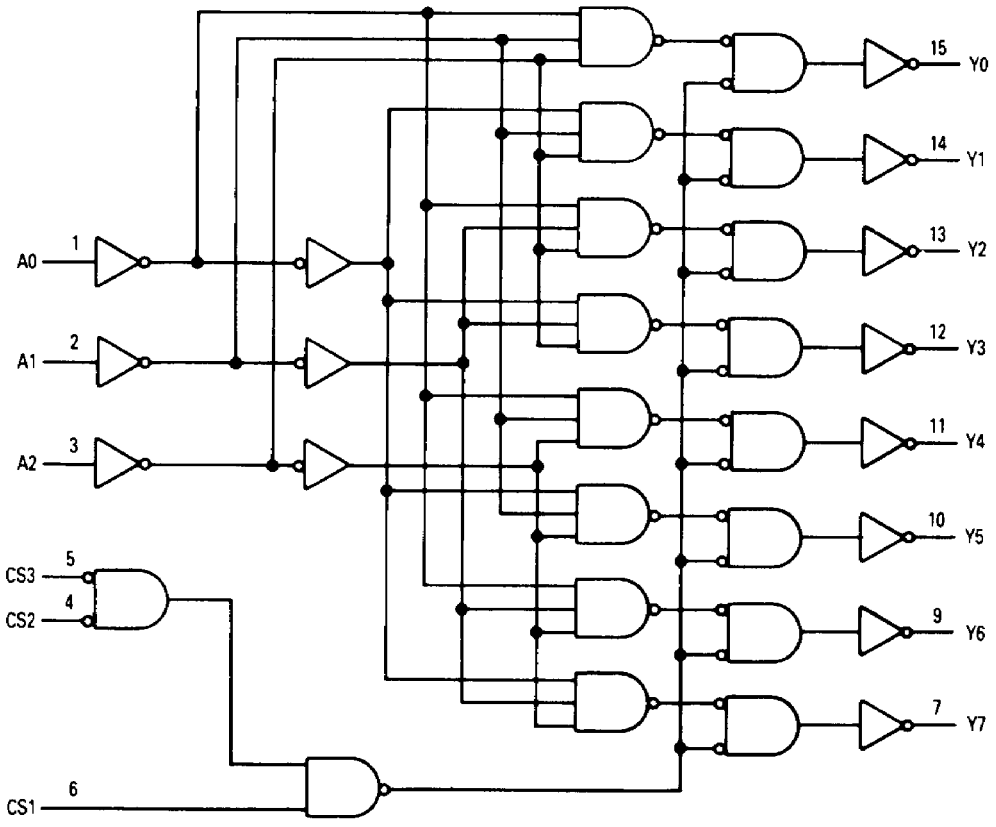


Figure 4. Test Circuit

EXPANDED LOGIC DIAGRAM